TPS53127 Dual Synchronous Step-Down Controller For Low Voltage Power Rails

1 Features

- D-CAP2™ Mode Control
  - Fast Transient Response
  - No External Parts Required for Loop Compensation
  - Compatible With Ceramic Output Capacitors
- High Initial Reference Accuracy (±1%)
- Low Output Ripple
- Wide Input Voltage Range: 4.5 V to 24 V
- Output Voltage Range: 0.76 V to 5.5 V
- Low-Side $R_{DS(ON)}$ Loss-Less Current Sensing
- Adaptive Gate Drivers with Integrated Boost Diode
- Adjustable Soft Start
- Non-Sinking Pre-Biased Soft Start
- 700-kHz Switching Frequency
- Cycle-by-Cycle Over-Current Limiting Control
- 30-mV to 300-mV OCP Threshold Voltage
- Thermally Compensated OCP by 4000 ppm/°C at I_{TRIP}

2 Applications

- Point-of-Load Regulation in Low Power Systems for Wide Range of Applications
  - Digital TV Power Supply
  - Networking Home Pin
  - Digital Set-Top Box (STB)
  - DVD Player/Recorder
  - Gaming Consoles

3 Description

The TPS53127 is a dual, adaptive on-time D-CAP2™ mode synchronous buck controller. The part enables system designers to cost effectively complete the suite of various end equipment's power bus regulators with a low external component count and low standby consumption. The main control loop for the TPS53127 uses the D-CAP2™ Mode topology which provides a very fast transient response with no external component.

The TPS53127 also has a proprietary circuit that enables the device to adapt not only low equivalent series resistance (ESR) output capacitors such as POSCAP/SP-CAP, but also ceramic capacitor. The part provides a convenient and efficient operation with conversion voltages from 4.5 V to 24 V and output voltage from 0.76 V to 5.5 V.

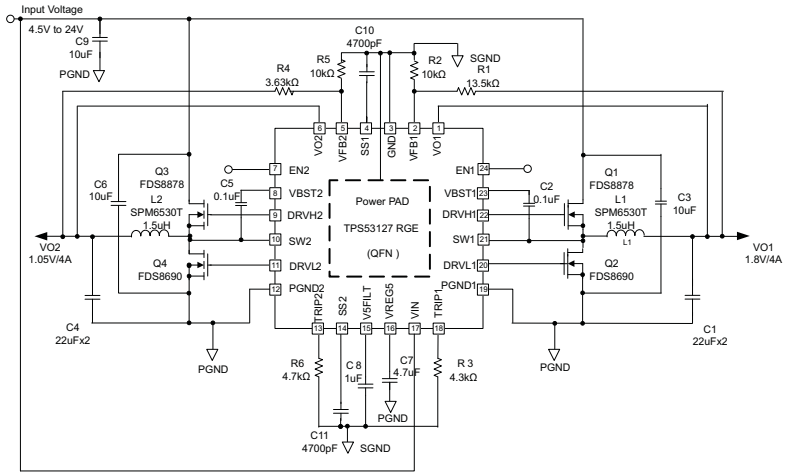
The TPS53127 is available in the 24 pin RGE/PW package, and is specified from –40°C to 85°C ambient temperature range.

Device Information(1)

DEVICE NAME	PACKAGE	BODY SIZE (NOM)
TPS53127	TSSOP (24)	7.80mm x 4.40mm
	VQFN (24)	4.00mm x 4.00mm

(1) For all available packages, see the orderable addendum at the end of the datasheet

4 Simplified Schematic



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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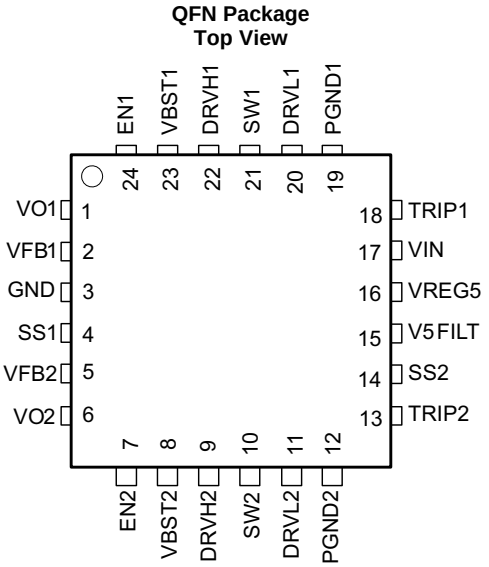
5 Revision History

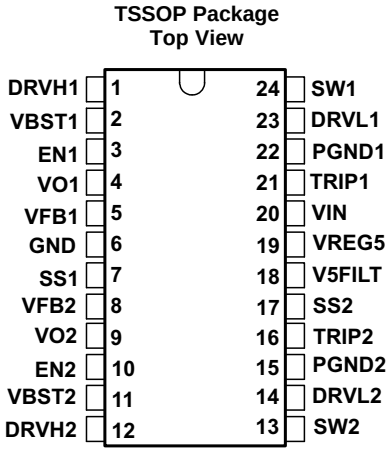
Changes from Original (March 2010) to Revision A **Page**

- Changed the data sheet to the new TI format ... 1
- Added T_A value to the Abs Max table ... 4
- Added the Handling Ratings table ... 4
- Added T_A value to the ROC table ... 4
- Added the Thermal Information table ... 5
- Changed the V_{VREG5} MIN value From: 4.8 V to 4.6 V ... 5
- Changed the R_{DRVL} MAX value for –100 mA From: 8 Ω To 12 Ω ... 5
- Changed the $I_{(SSC)}$ Min value From: -1.5 to -2.5 µA and the Max value From: -2.5 To: -1.5 µA ... 6
- Added the Timing Requirements table ... 6
- Added the Switching Characteristics table ... 6
- Added the Layout Example, Figure 28 ... 19

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6 Pin Configuration and Functions





Pin Functions

PIN			I/O	DESCRIPTION
NAME	QFN 24	TSSOP 24		
VBST1, VBST2	23, 8	2, 11	I	Supply input for high-side NFET driver. Bypass to SWx with a high-quality 0.1-µF ceramic capacitor. An external schottky diode can be added from VREG5 if forward drop is critical to drive the high-side FET.
EN1, EN2	24, 7	3, 10	I	Enable. Pull High to enable SMPS.
VO1, VO2	1, 6	4, 9	I	Output voltage inputs for on-time adjustment and output discharge. Connect directly to the output voltage.
VFB1, VFB2	2, 5	5, 8	I	D-CAP2 feedback inputs. Connect to output voltage with resistor divider.
GND	3	6	I	Signal ground pin. Connect to PGND1, PGND2 and system ground at a single point.
DRVH1, DRVH2	22, 9	1, 12	O	High-side N-Channel MOSFET gate driver outputs. SWx referenced drivers switch between SWx (OFF) and VBSTx (ON).
SW1, SW2	21, 10	24, 13	I/O	Switch node connections for both the high-side drivers and the over current comparators.
DRVL1, DRVL2	20, 11	23, 14	O	Low-side N-Channel MOSFET gate driver outputs. PGND referenced drivers switch between PGNDx (OFF) and VREG5 (ON).
PGND1, PGND2	19, 12	22, 15	I/O	Power ground connections for both the low-side drivers and the over current comparators. Connect PGND1, PGND2 and GND strongly together near the IC.
TRIP1, TRIP2	18, 13	21, 16	I	Over current threshold programming pin. Connect to GND with a resistor to GND to set threshold for low-side $R_{DS(ON)}$ current limit.
VIN	17	20	I	Supply Input for 5-V linear regulator. Bypass to GND with a minimum high-quality 0.1-µF ceramic capacitor.
V5FILT	15	18	I	5-V supply input for the entire control circuitry except the MOSFET drivers. Bypass to GND with a minimum high-quality 1.0-µF ceramic capacitor. V5FILT is connected to VREG5 via an internal 10-Ω resistor.
VREG5	16	19	O	Output of 5-V linear regulator and supply for MOSFET drivers. Bypass to GND with a minimum high-quality 4.7-µF ceramic capacitor. VREG5 is connected to V5FILT via an internal 10-Ω resistor.
SS1, SS2	4,14	7, 17	O	Soft-start programming pin. Connect capacitor from SSx pin to GND to program soft-start time.

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7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V_I	Input voltage range	VIN, EN1, EN2	–0.3	26	V
		VBST1, VBST2	–0.3	32	
		VBST1 - SW1, VBST2 - SW2	–0.3	6	
		V5FILT, VFB1, VFB2, TRIP1, TRIP2, VO1, VO2	–0.3	6	
		SW1, SW2	–2	26	
V_O	Output voltage range	DRVH1, DRVH2	–1	32	V
		DRVH1 - SW1, DRVH2 - SW2	–0.3	6	
		DRVL1, DRVL2, VREG5, SS1, SS2	–0.3	6	
		PGND1, PGND2	–0.3	0.3	
T_A	Operating free-air temperature		–40	85	°C
T_J	Junction temperature range		–40	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" are not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT
T_{STG}	Storage temperature range		–55	150	°C
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AN/ESDA/JEDEC JS-001, all pins (1)	–2000	2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	–500	500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{IN}	Supply input voltage	VIN	4.5	24	V
		V5FILT	4.5	5.5	
V_I	Input voltage	VBST1, VBST2	–0.1	30	V
		VBST1 - SW1, VBST2 - SW2	–0.1	5.5	
		VFB1, VFB2, VO1, VO2	–0.1	5.5	
		TRIP1, TRIP2	–0.1	0.3	
		EN1, EN2	–0.1	24	
		SW1, SW2	–1.8	24	
V_O	Output voltage	DRVH1, DRVH2	–0.1	30	V
		VBST1 - SW1, VBST2 - SW2	–0.1	5.5	
		DRVL1, DRVL2, VREG5, SS1, SS2	–0.1	5.5	
		PGND1, PGND2	–0.1	0.1	
T_A	Operating free-air temperature		–40	85	°C
T_J	Operating junction temperature		–40	125	°C

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7.4 Thermal Information

THERMAL METRIC(1)		TPS53127		UNIT
		PW 24 PINS	RGE 24 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	88.9	35.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	26.5	39.1	
$R_{\theta JB}$	Junction-to-board thermal resistance	43.5	13.6	
ψ_{JT}	Junction-to-top characterization parameter	1.1	0.5	
ψ_{JB}	Junction-to-board characterization parameter	43.0	13.6	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	3.8	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

7.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
I_{IN}	VIN supply current	VIN current, T_A = 25°C, VREG5 tied to V5FILT, EN1 = EN2 = 5 V, VFB1 = VFB2 = 0.8 V, SW1 = SW2 = 0.5 V		450	800	µA
$I_{(VINSDN)}$	VIN shutdown current	VIN current, T_A = 25°C, no load , EN1 = EN2 = 0 V, VREG5 = ON		30	60	µA
VFB VOLTAGE AND DISCHARGE RESISTANCE						
V_{BG}	Bandgap initial regulation accuracy	T_A = 25°C	–1		1	%
$V_{(VFBTHx)}$	VFBx threshold voltage	T_A = 25°C, SW_{inj} = OFF	748	758	768	mV
		TA = 0°C to 70°C, SW_{inj} = OFF(1)	746.6		769.4	
		T_A = -40°C to 85°C, SW_{inj} = OFF (1)	745		771	
$I_{(VFB)}$	VFB input current	VFBx = 0.8 V, T_A = 25°C	–100	–10	100	nA
$R_{(Dischg)}$	VO discharge resistancee	ENx = 0 V, VOx = 0.5 V, T_A = 25°C		40	80	Ω
VREG5 OUTPUT						
$V_{(VREG)5}$	VREG5 output voltage	T_A = 25°C, 5.5 V < VIN < 24 V, 0 < $I_{(VREG5)}$ < 10 mA	4.6	5.0	5.2	V
$V_{(LN5)}$	Line regulation	5.5 V < VIN < 24 V, $I_{(VREG5)}$ = 10 mA			20	mV
$V_{(LD5)}$	Load regulation	1 mA < $I_{(VREG5)}$ < 10 mA			40	mV
$I_{(VREG5)}$	Output current	VIN = 5.5 V, $V_{(REG5)}$ = 4.0 V, T_A = 25°C		170		mA
OUTPUT: N-CHANNEL MOSFET GATE DRIVERS						
$R_{(DRVH)}$	DRVH resistance	Source, $I_{(DRVHx)}$ = –100 mA		5.5	11	Ω
		Sink, $I_{(DRVHx)}$ = 100 mA		2.5	5	
$R_{(DRVL)}$	DRVL resistance	Source, $I_{(DRVLx)}$ = –100 mA		4	12	Ω
		Sink, $I_{(DRVLx)}$ = 100 mA		2	4	
INTERNAL BOOST DIODE						
$V_{(FBST)}$	Forward voltage	$V_{(VREG5-VBSTx)}$, I_F = 10 mA, T_A = 25°C	0.7	0.8	0.9	V
$I_{(VBSTLK)}$	VBST leakage current	VBSTx = 29 V, SWx = 24 V, T_A = 25°C		0.1	1	µA

(1) Not production tested - specified by design.

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Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SOFT START						
$I_{(SSC)}$	SS1/SS2 charge current	V_{SS1}/V_{SS2} = 0 V, T_A = 25°C	–2.5	–2	–1.5	µA
$TC_{(ISSC)}$	I_{SSC} temperature coefficient	On the basis of 25°C (2)	–4		3	nA/°C
I_{SSD}	SS1/SS2 discharge current	V_{SS1}/V_{SS2} = 0.5 V	100	150		µA
UVLO						
$V_{(UV5VFILT)}$	V5FILT UVLO threshold	Wake up	3.7	4.0	4.3	V
		Hysteresis	0.2	0.3	0.4	
LOGIC THRESHOLD						
$V_{(ENH)}$	ENx high-level input voltage	EN 1/2	2.0			V
$V_{(ENL)}$	ENx low-level input voltage	EN 1/2			0.3	V
CURRENT SENSE						
$I_{(TRIP)}$	TRIP source current	$V_{(TRIPx)}$ = 0.1 V, T_A = 25°C	8.5	10	11.5	µA
$TC_{(ITRIP)}$	I_{TRIP} temperature coefficient	On the basis of 25°C		4000		ppm/°C
$V_{OC(Loff)}$	OCP compensation offset	($V_{(TRIPx-GND)}$ - $V_{(PGNDx-SWx)}$) voltage, $V_{(TRIPx-GND)}$ = 60 mV, T_A = 25°C	–15	0	15	mV
		($V_{(TRIPx-GND)}$ - $V_{(PGNDx-SWx)}$) voltage, $V_{(TRIPx-GND)}$ = 60 mV	–20		20	
$V_{R(trip)}$	Current limit threshold setting range	$V_{(TRIPx-GND)}$ voltage	30		300	mV
OUTPUT UNDERVOLTAGE AND OVERVOLTAGE PROTECTION						
V_{OVP}	Output OVP trip threshold	OVP detect	110	115	120	%
V_{UVP}	Output UVP trip threshold	UVP detect	65	70	75	%
		Hysteresis (recover < 20 µs)		10		
THERMAL SHUTDOWN						
T_{SDN}	Thermal shutdown threshold	Shutdown temperature (2)		150		°C
		Hysteresis (2)		20		

(2) Not production tested - specified by design.

7.6 Timing Requirements

			MIN	TYP	MAX	UNIT
OUTPUT: N-CHANNEL MOSFET GATE DRIVERS						
t_D	Dead time	DRVHx-low to DRVLx-on	20	50	80	ns
		DRVLx-low to DRVHx-on	20	40	80	ns
OUTPUT UNDERVOLTAGE AND OVERVOLTAGE PROTECTION						
t_{OVPDEL}	Output OVP prop delay			1.5		µs
t_{UVPDEL}	Output UVP delay		17	30	40	µs
t_{UVPEN}	Output UVP enable delay	UVP enable delay / soft-start time	x1.4	x1.7	x2.0	ms

7.7 Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

			MIN	TYP	MAX	UNIT
ON-TIME TIMER CONTROL						
t_{ON1L}	CH1 on time	SW1 = 12 V, VO1 = 1.8 V		165		ns
t_{ON2L}	CH2 on time	SW2 = 12 V, VO2 = 1.8 V		140		ns
t_{OFF1L}	CH1 min off time	SW1 = 0.7 V, T_A = 25°C, VFB1 = 0.7 V		216		ns
t_{OFF2L}	CH2 min off time	SW2 = 0.7 V, T_A = 25°C, VFB2 = 0.7 V		216		ns

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7.8 Typical Characteristics

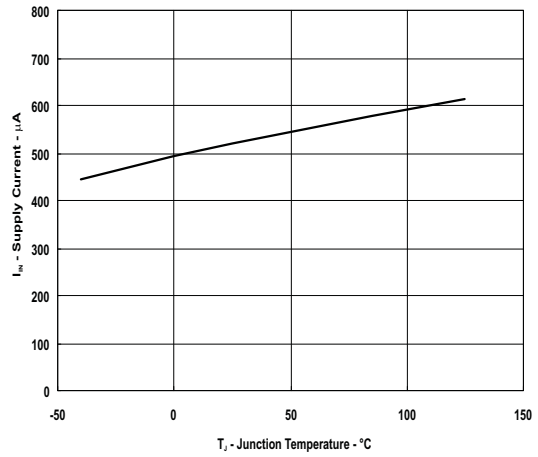


Figure 1. V_{IN} Supply Current vs Junction Temperature

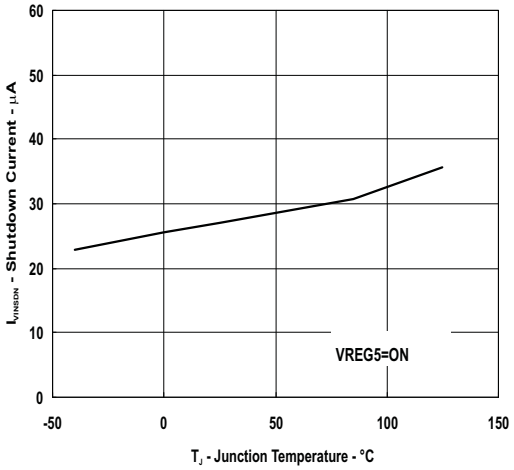


Figure 2. V_{IN} Shutdown Current vs Junction Temperature

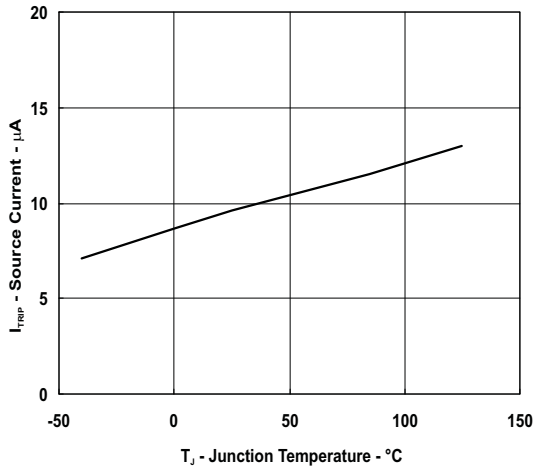


Figure 3. Trip Source Current vs Junction Temperature

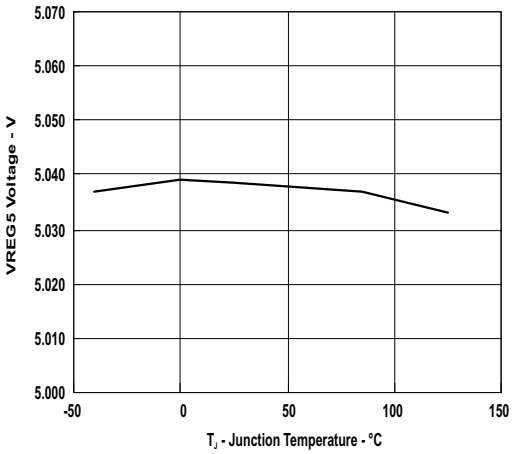


Figure 4. VREG5 Voltage vs Junction Temperature

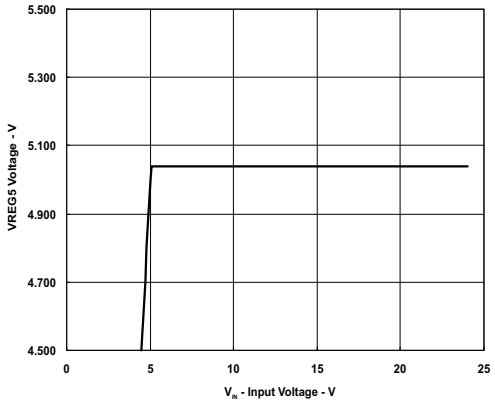


Figure 5. VREG5 Voltage vs Input Voltage

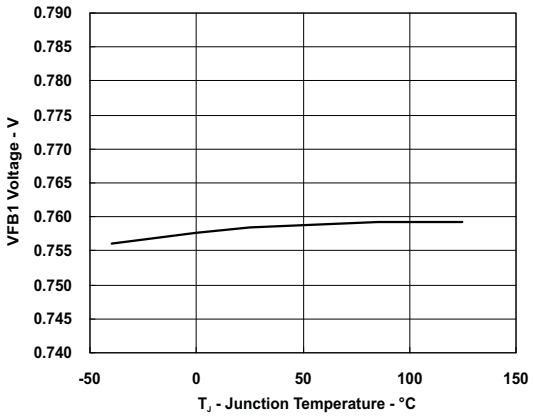


Figure 6. VFB1 Voltage vs Junction Temperature

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Typical Characteristics (continued)

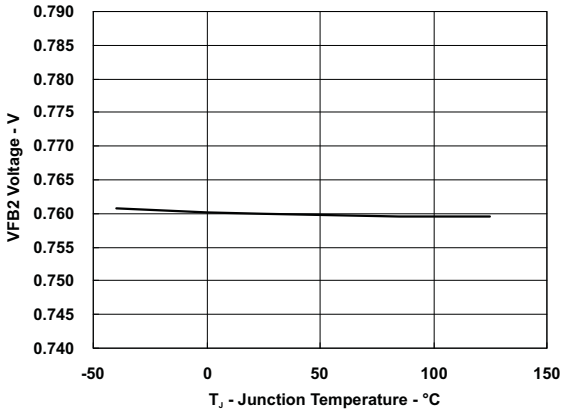


Figure 7. VFB2 Voltage vs Junction Temperature

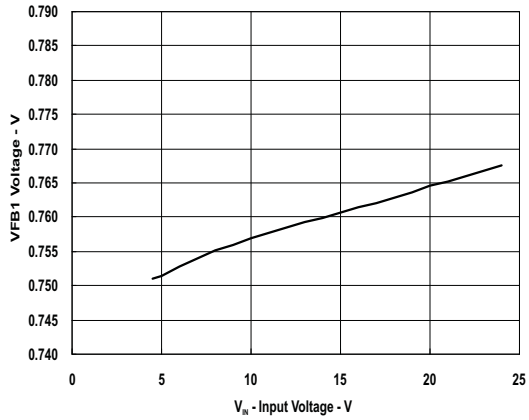


Figure 8. VFB1 Voltage vs Input Voltage

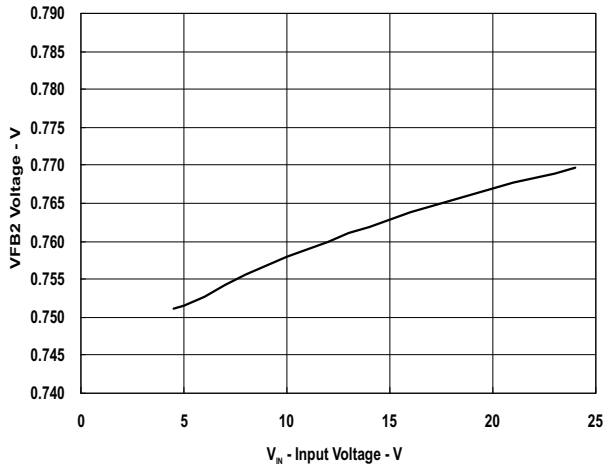


Figure 9. VFB2 Voltage vs Input Voltage

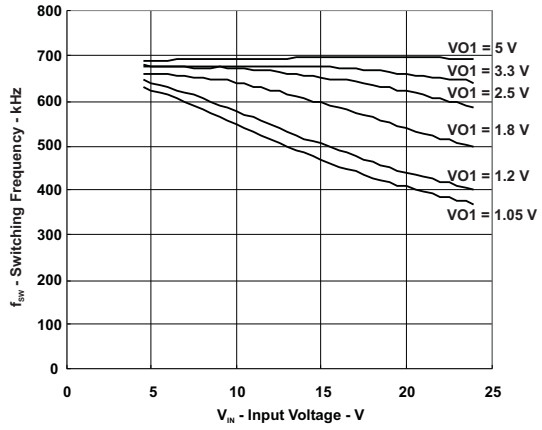


Figure 10. Switching Frequency (I_O1 = 3 A) vs Input Voltage (CH1)

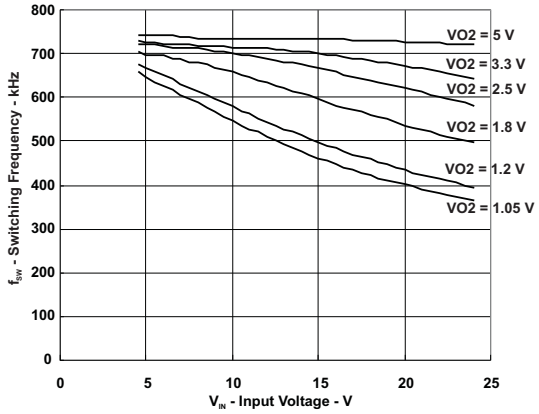


Figure 11. Switching Frequency (I_O2 = 3 A) vs Input Voltage (CH2)

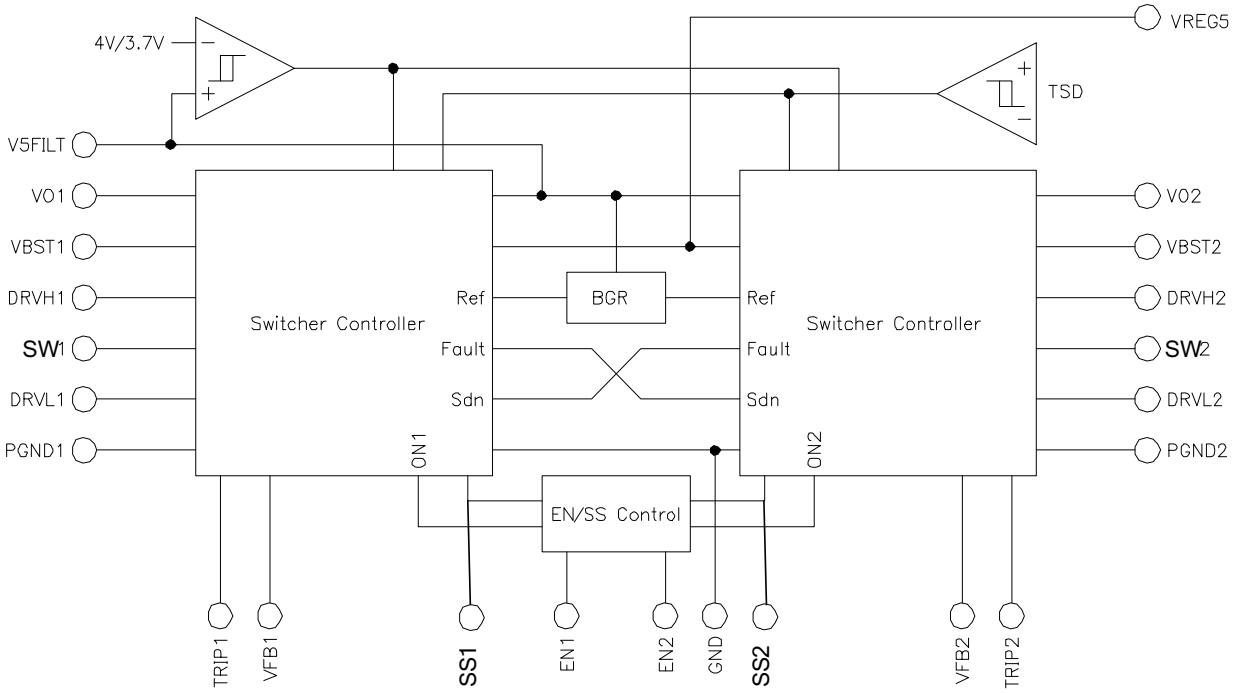
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8 Detailed Description

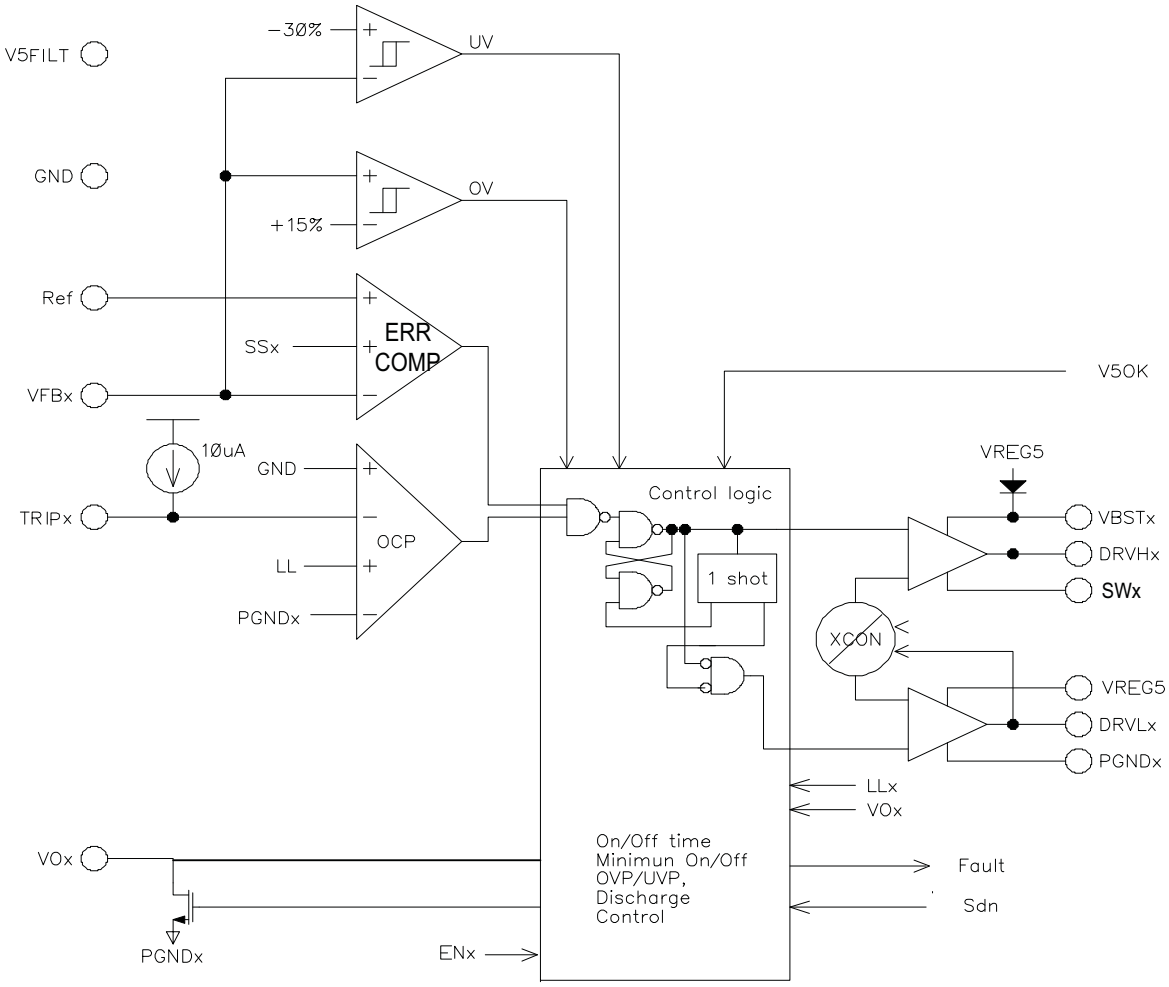
8.1 Overview

The TPS53127 is a dual, adaptive on-time D-CAP2™ mode synchronous Buck controller. The main control loop for the TPS53127 uses the D-CAP2™ mode control which provides a fast transient response with no external components. The TPS53127 also has a proprietary circuit that enables the device to adapt to both low equivalent series resistance (ESR) output capacitors, such as POSCAP or SP-CAP, and ultra-low ESR ceramic capacitors. The device provides convenient and efficient operation with input voltages from 4.5 V to 24 V and output voltages from 0.76 V to 5.5 V.

8.2 Functional Block Diagram



Functional Block Diagram (continued)



8.3 Feature Description

8.3.1 PWM Operation

The main control loop of the TPS53127 is an adaptive on-time pulse width modulation (PWM) controller using a proprietary D-CAP2™ mode control. D-CAP2™ mode control combines constant on-time control with an internal compensation circuit for pseudo-fixed frequency and low external component count configuration with both low ESR and ceramic output capacitors. It is stable even with virtually no ripple at the output.

At the beginning of each cycle, the synchronous high-side MOSFET is turned on. After an internal one-shot timer expires, this MOSFET is turned off. When the feedback voltage falls below the reference voltage, the one-shot timer is reset and the high-side MOSFET is turned back on. The one shot is set by the converter input voltage VIN, and the output voltage VO, to maintain a pseudo-fixed frequency over the input voltage range. An internal ramp is added to the reference voltage to simulate output ripple, eliminating the need for ESR induced output ripple from D-CAP mode control.

8.3.2 Drivers

Each channel of the TPS53127 contains two high-current resistive MOSFET gate drivers. The low-side driver is a PGND referenced, VREG5 powered driver designed to drive the gate of a high-current, low $R_{DS(ON)}$ N-channel MOSFET whose source is connected to PGND. The high-side driver is a floating SWx referenced VBST powered driver designed to drive the gate of a high-current, low $R_{DS(ON)}$ N-channel MOSFET. To maintain the VBST voltage during the high-side driver ON time, a capacitor is placed from SWx to VBSTx. Each driver draws average current equal to gate charge (Q_g at V_{gs} = 5 V) times switching frequency (f_{SW}).

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Feature Description (continued)

To prevent cross-conduction, there is a narrow dead-time when both high-side and low-side drivers are OFF between each driver transition. During this time the inductor current is carried by one of the MOSFETs body diodes.

8.3.3 PWM Frequency and Adaptive On-Time Control

TPS53127 employs adaptive on-time control scheme and does not have a dedicated on board oscillator.

TPS53127 runs with pseudo-constant frequency by using the input voltage and output voltage to set the on-time one-shot timer. The on-time is inversely proportional to the input voltage and proportional to the output voltage. Therefore, when the duty ratio is VOUT/VIN, the frequency is constant.

8.3.4 5-Volt Regulator

The TPS53127 has an internal 5-V low-dropout (LDO) regulator to provide a regulated voltage for all both drivers and the IC's internal logic. A high-quality 4.7-µF or greater ceramic capacitor from VREG5 to GND is required to stabilize the internal regulator. An internal 10-Ω resistor from VREG5 filters the regulator output to the IC's analog and logic input voltage, V5FILT. An additional high-quality 1.0-µF ceramic capacitor is required from V5FILT to GND to filter switching noise from VREG5.

8.3.5 Soft Start

The TPS53127 has a programmable soft-start . When the ENx pin becomes high, 2.0-µA current begins charging the capacitor connected from the SS pin to GND. The internal reference for the D-CAP2™ mode control comparator is overridden by the soft-start voltage until the soft-start voltage is greater than the internal reference for smooth control of the output voltage during start up.

8.3.6 Pre-Bias Support

The TPS53127 supports pre-bias start-up without sinking current from the output capacitor. When enabled, the low-side driver is held off until the soft-start commands a voltage higher than the pre-bias level (internal soft-start becomes greater than feedback voltage (VFB)), then the TPS53127 slowly activates synchronous rectification by limiting the first DRVL pulses with a narrow on-time. This limited on-time is then incremented on a cycle-by-cycle basis until it coincides with the full 1-D off-time. This scheme prevents the initial sinking of current from the pre-bias output, and ensure that the output voltage (VOUT) starts and ramps up smoothly into regulation and the control loop is given time to transition from pre-biased start-up to normal mode operation.

8.3.7 Output Discharge Control

TPS53127 discharges the outputs when ENx is low, or the controller is turned off by the protection functions (OVP, UVP, UVLO, and thermal shutdown). The device discharges output using an internal 40-Ω MOSFET which is connected to VOx and PGNDx. The external low-side MOSFET is not turned on during the output discharge operation to avoid the possibility of causing negative voltage at the output. This discharge ensures that on start the regulated voltage always initializes from 0 V.

8.3.8 Over Current Limit

TPS53127 has cycle-by-cycle over current limit feature. The over current limits the inductor valley current by monitoring the voltage drop across the low-side MOSFET $R_{DS(ON)}$ during the low-side driver on-time. If the inductor current is larger than the over current limit (OCL), the TPS53127 delays the start of the next switching cycle until the sensed inductor current falls below the OCL current. MOSFET $R_{DS(ON)}$ current sensing is used to provide an accuracy and cost effective solution without external devices. To program the OCL, the TRIP pin should be connected to GND through a trip voltage setting resistor, according to the following equations.

$$V_{TRIP} = \left(I_{OCL} - \frac{(V_{IN} - V_O)}{2 \bullet L1 \bullet f_{SW}} \bullet \frac{V_O}{V_{IN}} \right) \bullet R_{DS(ON)} \quad (1)$$

$$R_{TRIP}\,(k\Omega) = \frac{V_{TRIP}\,(mV)}{I_{TRIP}\,(\mu A)} \quad (2)$$

Feature Description (continued)

The trip voltage should be between 30 mV to 300 mV over all operational temperature, including the 4000-ppm/°C temperature slope compensation for the temperature dependency of the $R_{DS(ON)}$.

If the load current exceeds the over current limit, the voltage will begin to drop. If the over current conditions continues the output voltage will fall below the under voltage protection threshold and the TPS53127 will shut down.

In an over current condition, the current to the load exceeds the current to the output capacitor; thus the output voltage tends to fall off. Eventually, it will end up with crossing the under voltage protection threshold and shutdown.

8.3.9 Over/Under Voltage Protection

TPS53127 monitors a resistor divided feedback voltage to detect over and under voltage. If the feedback voltage is higher than 115% of the reference voltage, the OVP comparator output goes high and the circuit latches the high-side MOSFET driver OFF and the low-side MOSFET driver ON.

When the feedback voltage is lower than 70% of the reference voltage, the UVP comparator output goes high and an internal UVP delay counter begins counting. After 30 µs, TPS53127 latches OFF both top and bottom MOSFET drivers. This function is enabled approximately 1.7 x T_{SS} after power-on. The OVP and UVP latch off is reset when EN goes low level.

8.3.10 UVLO Protection

TPS53127 has V5FILT under voltage lock out protection (UVLO) that monitors the voltage of V5FILT pin.

When the V5FILT voltage is lower than UVLO threshold voltage, the device is shut off. All output drivers are OFF and output discharge is ON. The UVLO is non-latch protection.

8.3.11 Thermal Shutdown

The TPS53127 includes an over temperature protection shut-down feature. If the TPS53127 die temperature exceeds the OTP threshold (typically 150°C), both the high-side and low-side drivers are shut off, the output voltage discharge function is enabled and then the device is shut off until the die temperature drops. Thermal shutdown is a non-latch protection.

8.4 Device Functional Modes

The TPS53127 has two operating modes. The TPS53127 is in shut down mode when the EN1 and EN2 pins are low. When the EN1 and EN2 pins is pulled high, the TPS53127 enters the normal operating mode.

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9 Application and Implementation

9.1 Application Information

9.2 Typical Application, QFN

The TPS53127 is a Dual D-CAP2™ Mode Control Step-Down Controller in a realistic cost-sensitive application. Providing both a low core-type 1.05 V and I/O type 1.8 V output from a loosely regulated 12 V source. Idea applications are: Digital TV Power Supply, Networking Home Pin, Digital Set-Top Box (STB), DVD Player/Recorder, and Gaming Consoles.

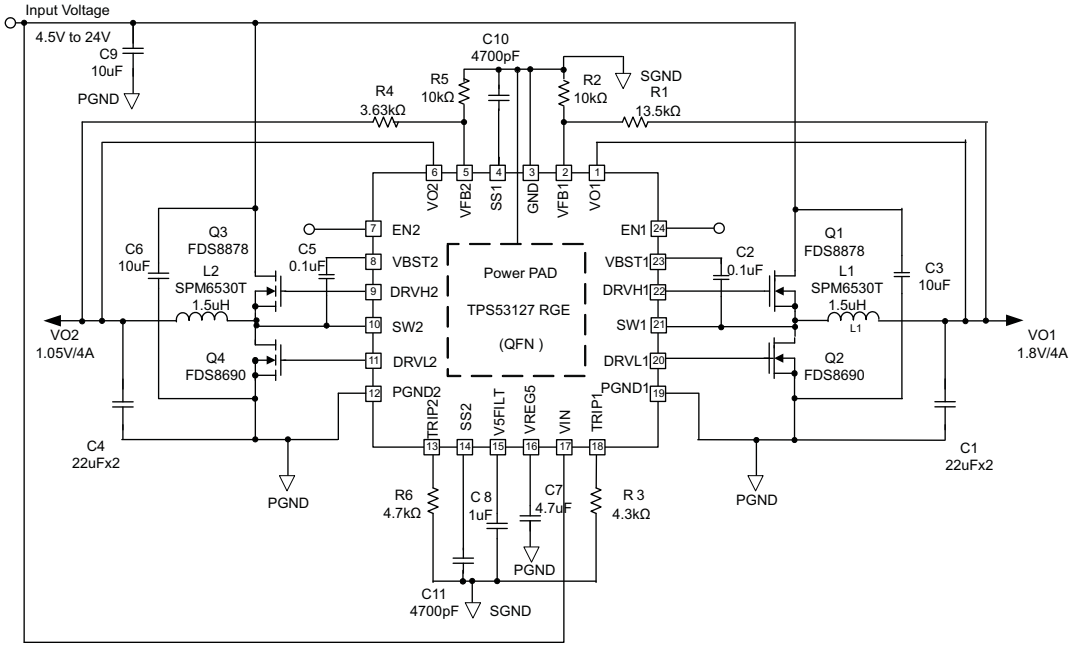


Figure 12. Typical Application Circuit

9.2.1 Design Requirements (QFN)

Table 1. Design Parameters

PARAMETERS	EXAMPLE VALUES
Input voltage	12 V
Output voltage	VO1 = 1.8 V, VO2 = 1.05 V

9.2.2 Detailed Design Procedure (QFN)

9.2.2.1 Choose Inductor

The inductance value is selected to provide approximately 30% peak to peak ripple current at maximum load. Larger ripple current increases output ripple voltage, improve S/N ratio and contribute to stable operation.

Equation 3 can be used to calculate L1.

$$L1 = \frac{(V_{IN(MAX)} - V_O1)}{I_{L1(RIPPLE)} \bullet f_{SW}} \bullet \frac{V_O1}{V_{IN(MAX)}} = \frac{(V_{IN(MAX)} - V_O1)}{0.3 \bullet I_O1 \bullet f_{SW}} \bullet \frac{V_o1}{V_{IN(MAX)}} \quad (3)$$

The inductors current ratings needs to support both the RMS (thermal) current and the Peak (saturation) current. The RMS and peak inductor current can be estimated as follows.

$$I_{L1(RIPPLE)} = \frac{V_{IN(MAX)} - V_O1}{L1 \bullet f_{SW}} \bullet \frac{V_o1}{V_{IN(MAX)}} \quad (4)$$

$$I_{L1(PEAK)} = \frac{V_{TRIP}}{R_{DS(ON)}} + I_{L1(RIPPLE)} \quad (5)$$

$$I_{L1(RMS)} = \sqrt{I_O1^2 + \frac{1}{12}(I_{L1(RIPPLE)})^2} \quad (6)$$

Note: The calculation above shall serve as a general reference. To further improve transient response, the output inductance could be reduced further. This needs to be considered along with the selection of the output capacitor.

9.2.2.2 Choose Output Capacitor

The capacitor value and ESR determines the amount of output voltage ripple and load transient response. it is recommended to use a ceramic output capacitor.

$$C1 = \frac{I_{L1(RIPPLE)}}{8 \bullet V_O1_{(RIPPLE)}} \bullet \frac{1}{f_{SW}} \quad (7)$$

$$C1 = \frac{\Delta I_{load}^{\ 2} \bullet L1}{2 \bullet V_O1 \bullet \Delta V_{OS}} \quad (8)$$

$$C1 = \frac{\Delta I_{load}^{\ 2} \bullet L1}{2 \bullet K \bullet \Delta V_{US}} \quad (9)$$

Where

$$K = (V_{IN} - V_O1) \bullet \frac{T_{on}1}{T_{on}1 + T_{min(off)}} \quad (10)$$

Select the capacitance value greater than the largest value calculated from Equation 7, Equation 8 and Equation 9. The capacitance for C1 should be greater than 66 µF.

Where

- ΔV_{OS} = The allowable amount of overshoot voltage in load transition.
- ΔV_{US} = The allowable amount of undershoot voltage in load transition.
- $t_{min(off)}$ = Minimum off time

9.2.2.3 Choose Input Capacitor

The TPS53127 requires an input decoupling capacitor and a bulk capacitor is needed depending on the application. A minimum 10-µF high-quality ceramic capacitor is recommended for the input capacitor. The capacitor voltage rating needs to be greater than the maximum input voltage.

9.2.2.4 Choose Bootstrap Capacitor

The TPS53127 requires a bootstrap capacitor from SW to VBST to provide the floating supply for the high-side drivers. A minimum 0.1-µF high-quality ceramic capacitor is recommended. The voltage rating should be greater than 10 V.

9.2.2.5 Choose VREG5 and V5FILT Capacitor

The TPS53127 requires both the VREG5 regulator and V5FILT input are bypassed. A minimum 4.7-µF high-quality ceramic capacitor must be connected between the VREG5 and GND for proper operation. A minimum 1-µF high-quality ceramic capacitor must be connected between the V5FILT and GND for proper operation. Both of these capacitors' voltage ratings should be greater than 10 V.

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9.2.2.6 Choose Output Voltage Set Point Resistors

The output voltage is set with a resistor divider from the output voltage node to the VFBx pin. It is recommended to use 1% tolerance or better resisters. Select R2 between 10 kΩ and 100 kΩ and use Equation 11 or Equation 12 to calculate R1.

$$V_{swinj} = (V_{IN} - V_O1 \bullet 0.5875) \bullet \left(\frac{1}{f_{SW}}\right) \bullet \left(\frac{V_O1}{V_{IN}}\right) \bullet 10127 \quad (11)$$

$$R1 = \left(\frac{V_O1}{V_{FB} + \frac{V_{FB(RIPPLE)} + V_{swinj}}{2}} - 1\right) \bullet R2 \quad (12)$$

Where

$V_{FB(RIPPLE)}$ = Ripple voltage at VFB
V_{swinj} = Ripple voltage at error comparator

9.2.2.7 Choose Over Current Set Point Resistor

$$V_{TRIP} = \left(I_{OCL} - \frac{(V_{IN} - V_O)}{2 \bullet L1 \bullet f_{SW}} \bullet \frac{V_O}{V_{IN}}\right) \bullet R_{DS(ON)} \quad (13)$$

$$R_{TRIP}\,(k\Omega) = \frac{V_{TRIP}\,(mV) - V_{OCLoff}}{I_{TRIP(min)}\,(\mu A)} \quad (14)$$

Where:

- $R_{DS(ON)}$ = Low side FET on-resistance
- $I_{TRIP(min)}$ = TRIP pin source current (8.5 µA)
- V_{OCL0ff} = Minimum over current limit offset voltage (–20 mV)
- I_{OCL} = Over current limit

9.2.2.8 Choose Soft Start Capacitor

Soft start time equation is as follows.

$$C_{SS} = \frac{T_{SS} \bullet I_{SSC}}{V_{FB}} \quad (15)$$

9.2.3 Application Curves (QFN)

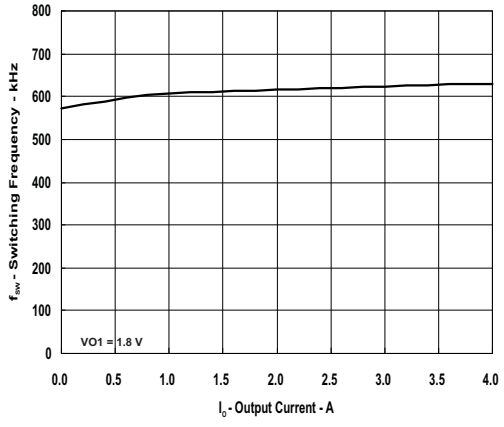


Figure 13. Switching Frequency (V_{IN} = 12 V) vs Output current (CH1)

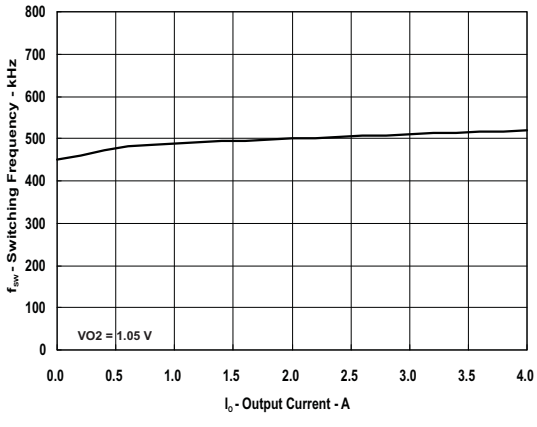


Figure 14. Switching Frequency (V_{IN} = 12 V) vs Output Current (CH2)

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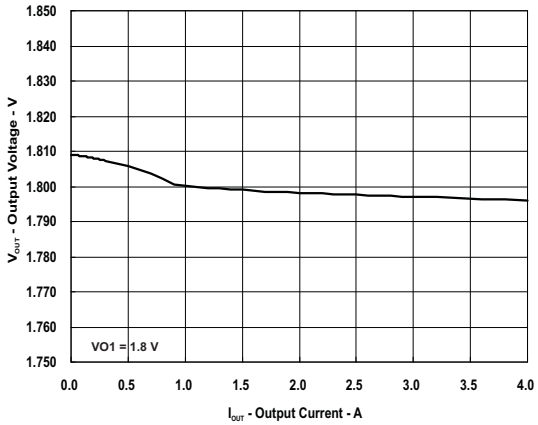


Figure 15. Output Voltage (V_{IN} = 12 V) vs Output Current (CH1)

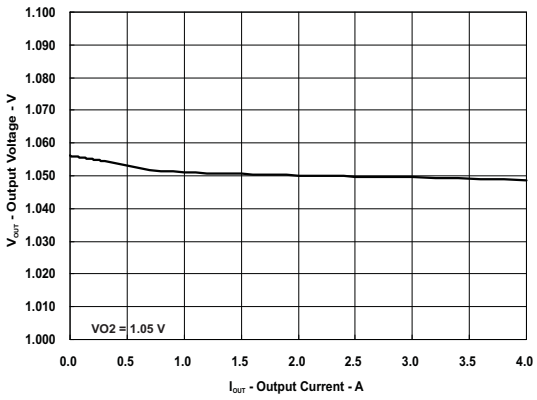


Figure 16. Output Voltage (V_{IN} = 12 V) vs Output Current (CH2)

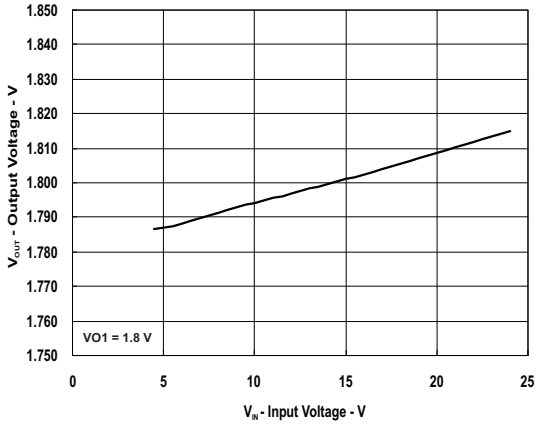


Figure 17. Output Voltage (V_{IN} = 12 V) vs Input Voltage (CH1)

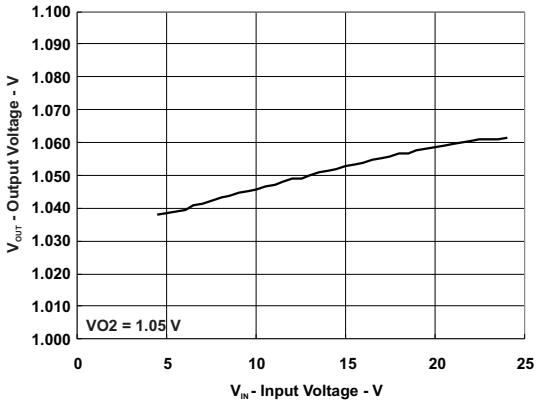


Figure 18. Output Voltage (V_{IN} = 12 V) vs Input Voltage (CH2)

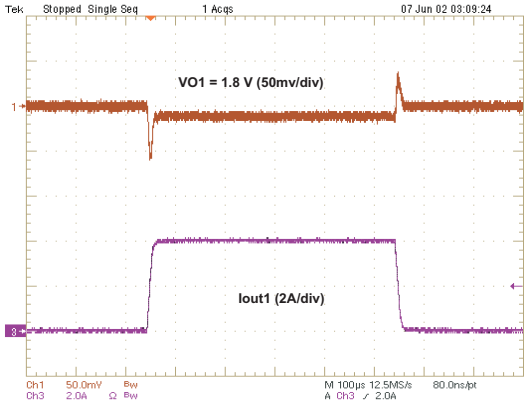


Figure 19. Load Transient Response

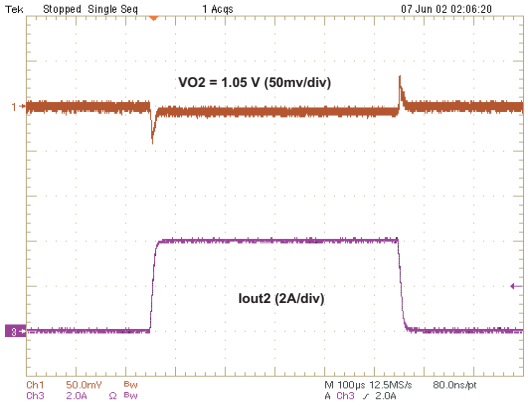


Figure 20. Load Transient Response

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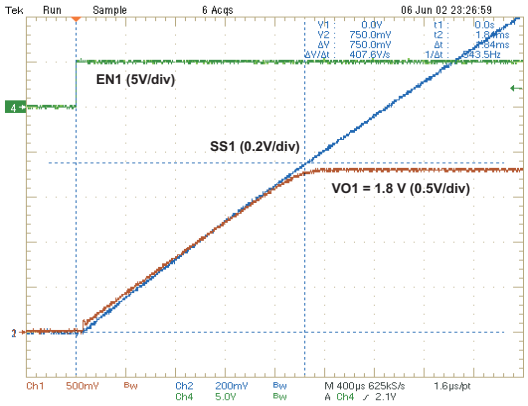


Figure 21. Start-Up Waveforms

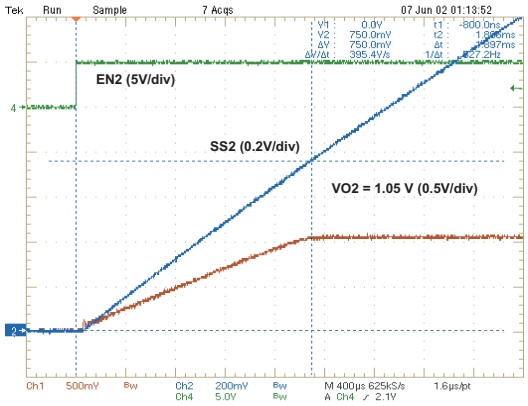


Figure 22. Start-Up Waveforms

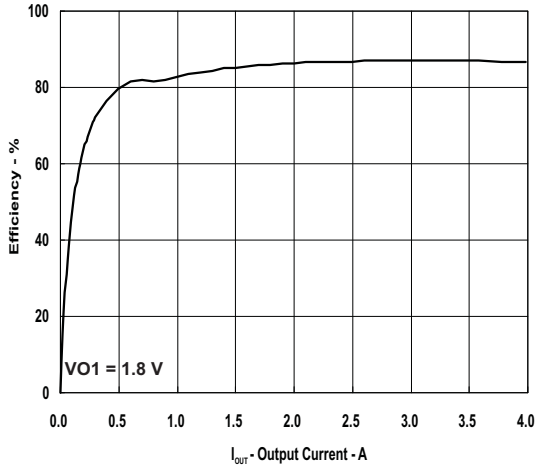


Figure 23. 1.8 V Efficiency vs Output Current (CH1)

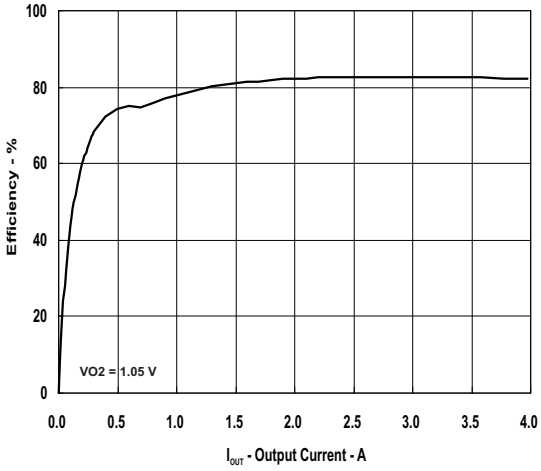


Figure 24. 1.05 V Efficiency vs Output Current (CH2)

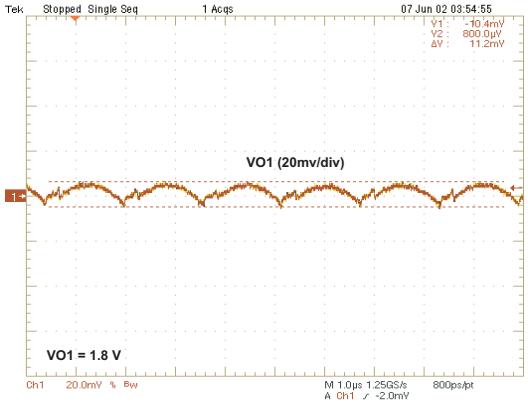


Figure 25. 1.8-V Output Ripple Voltage

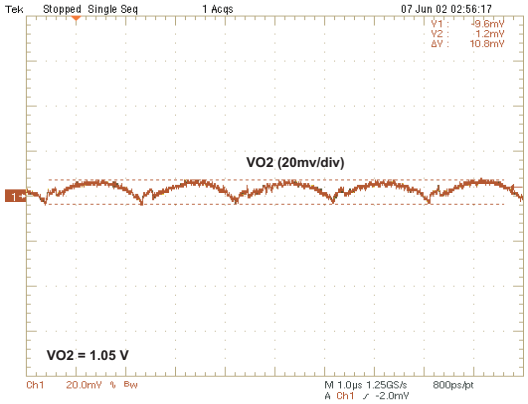


Figure 26. 1.05-V Output Ripple Voltage

9.3 Typical Application Circuit, TSSOP

The TPS53127is a Dual D-CAP2™ Mode Control Step-Down Controller in a realistic cost-sensitive application. Providing both a low core-type 1.05 V and I/O type 1.8V output from a loosely regulated 12 V source.

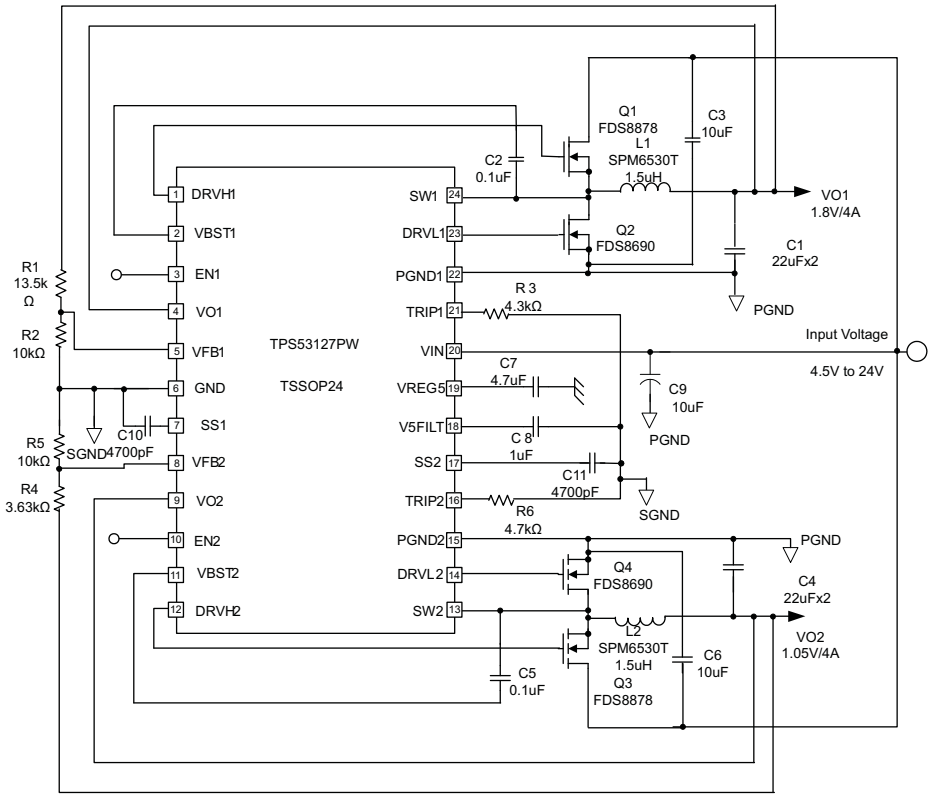


Figure 27. Typical Application Circuit

9.3.1 Design Requirements

For the Design Requirements, refer to *Design Requirements (QFN)*.

9.3.2 Detailed Design Procedure

For the Detailed Design Procedure, refer to *Detailed Design Procedure (QFN)*.

9.3.3 Application Curves

For the Application Curves, refer to *Application Curves (QFN)*.

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10 Power Supply Recommendations

The devices are designed to operate from an input voltage supply range between 4.5 V and 24 V. This input supply must be well regulated. If the input supply is located more than a few inches from the TPS53127 device additional 0.1 µF ceramic capacitance may be required in addition to the ceramic bypass capacitors, 10 µF.

11 Layout

11.1 Layout Guidelines

- Keep the input switching current loop as small as possible. (VIN ≥ C3 ≥ PNGD ≥ Sync FET ≥ SW ≥ Control FET)
- Place the input capacitor (C3) close to the top switching FET. The output current loop should also be kept as small as possible.
- Keep the SW node as physically small and short as possible as to minimize parasitic capacitance and inductance and to minimize radiated emissions. Kelvin connections should be brought from the output to the feedback terminal (FBx) of the device.
- Keep analog and non-switching components away from switching components.
- Make a single point connection from the signal ground to power ground.(1)
- Do not allow switching current to flow under the device.
- DRVH and DRVL line should not run close to SW node or minimize it. (2)
- GND terminals for capacitors of SSx and V5FILT and resistors of feedback and TRIPx should be connected to SGND. (3)
- GND terminals for capacitors of VREG5 and VIN should be connected to PGND. (4)
- Signal lines should not run under/near Output Inductor or minimize it. (5)

11.2 Layout Example

Reference designators shown correspond to the schematic of Figure 28.

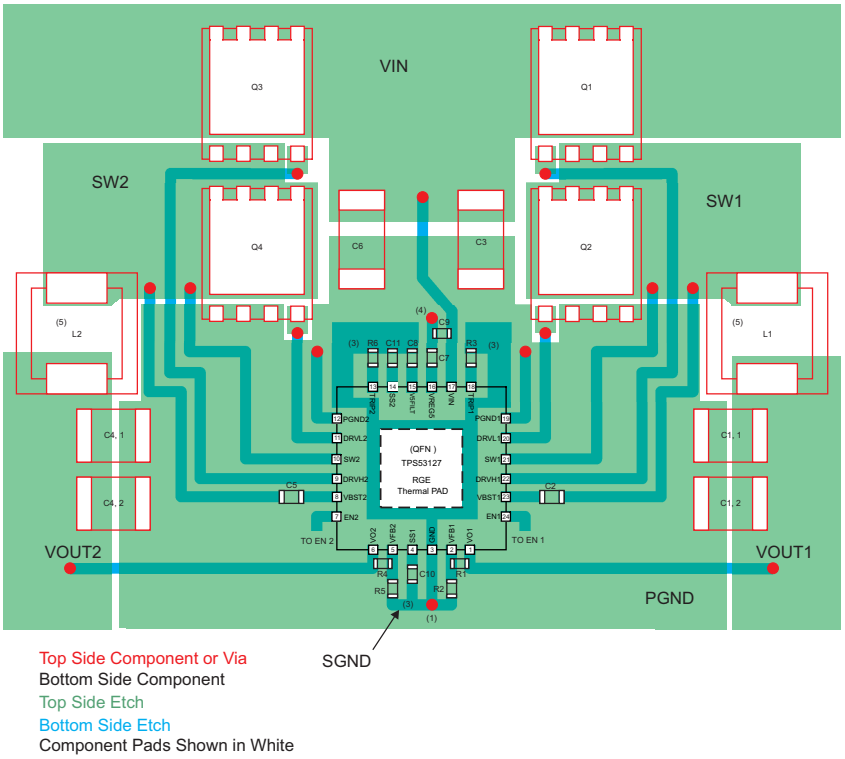


Figure 28. Board Layout

12 Device and Documentation Support

12.1 Trademarks

D-CAP2 is a trademark of Texas Instruments.

12.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.3 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS53127PW	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PS53127	Samples
TPS53127PWR	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PS53127	Samples
TPS53127RGER	ACTIVE	VQFN	RGE	24	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TPS 53127	Samples
TPS53127RGET	ACTIVE	VQFN	RGE	24	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TPS 53127	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

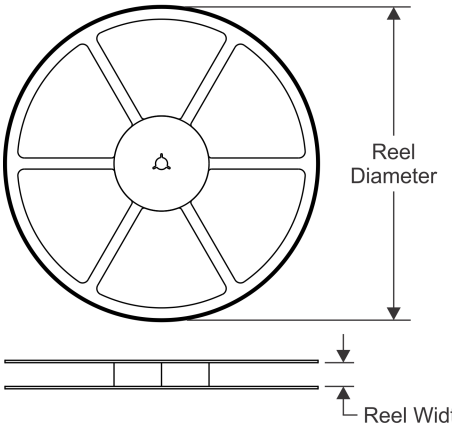
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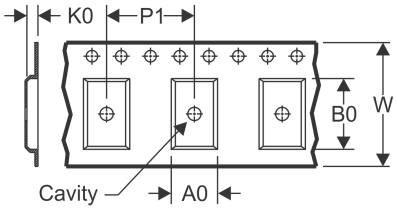
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

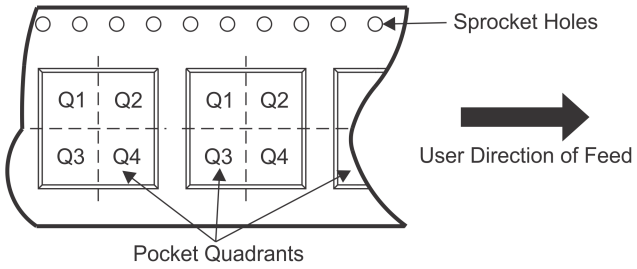


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

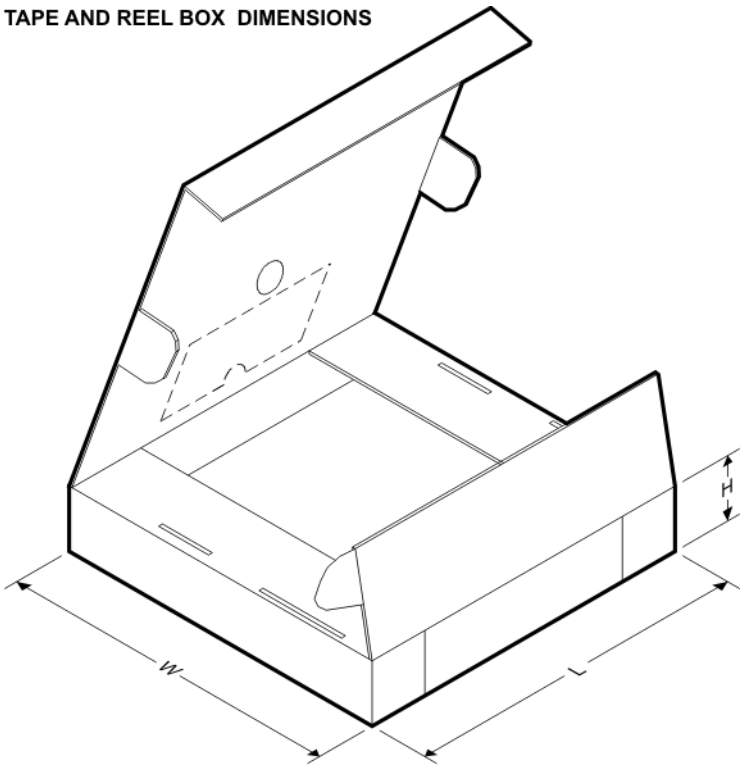
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS53127PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
TPS53127RGER	VQFN	RGE	24	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2
TPS53127RGET	VQFN	RGE	24	250	180.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

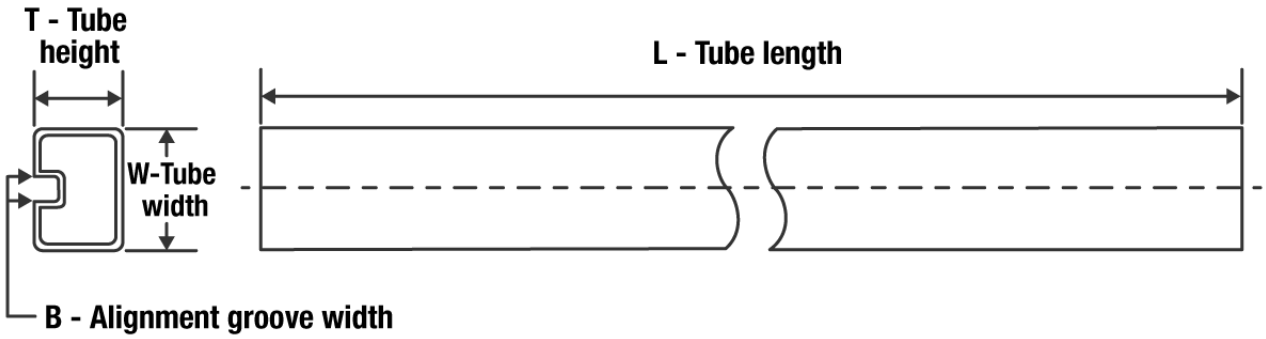
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS53127PWR	TSSOP	PW	24	2000	853.0	449.0	35.0
TPS53127RGER	VQFN	RGE	24	3000	853.0	449.0	35.0
TPS53127RGET	VQFN	RGE	24	250	210.0	185.0	35.0

TUBE



*All dimensions are nominal

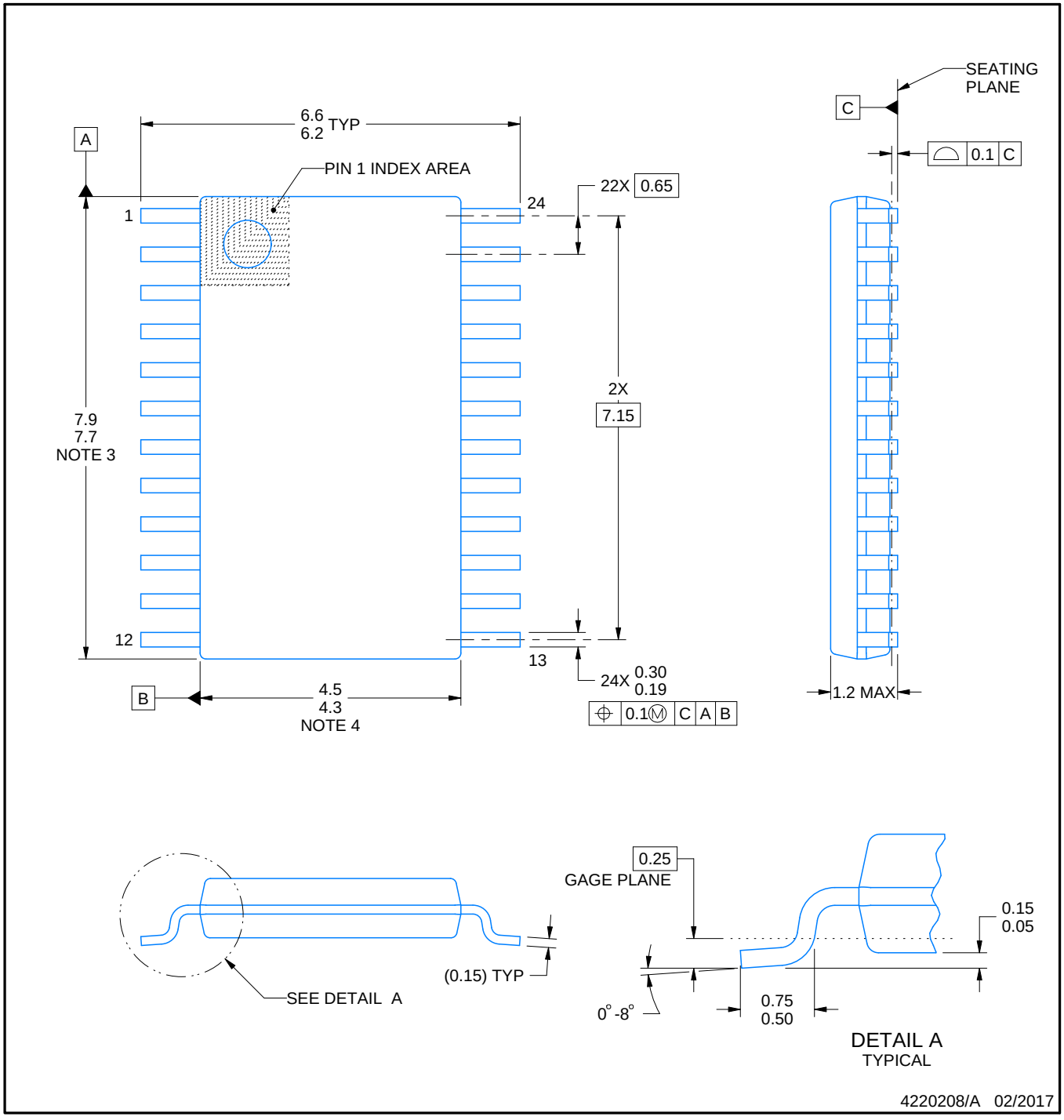
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TPS53127PW	PW	TSSOP	24	60	530	10.2	3600	3.5

PACKAGE OUTLINE

PW0024A

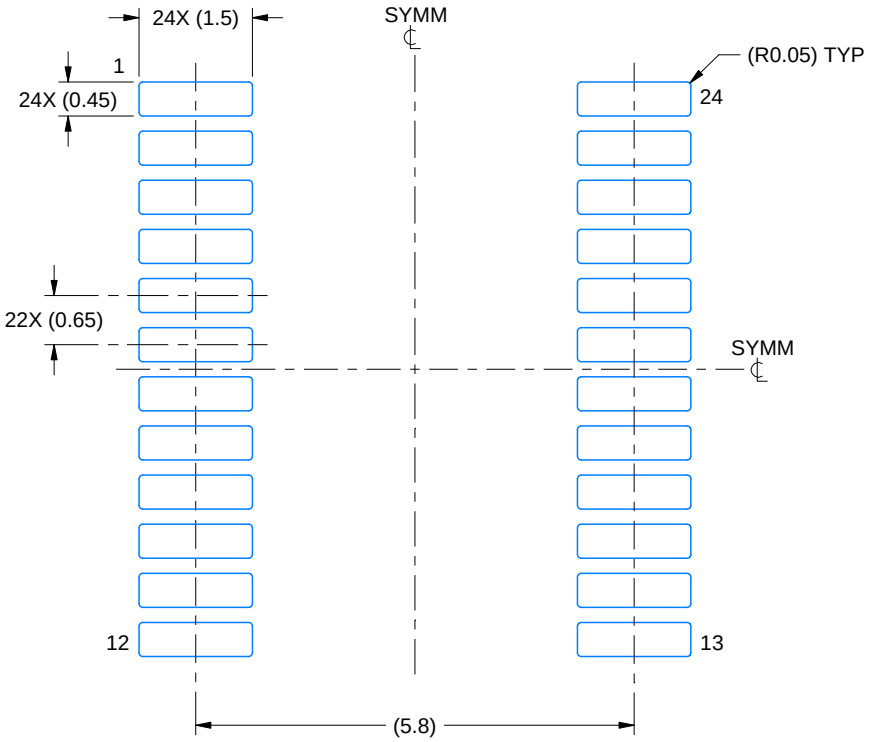
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

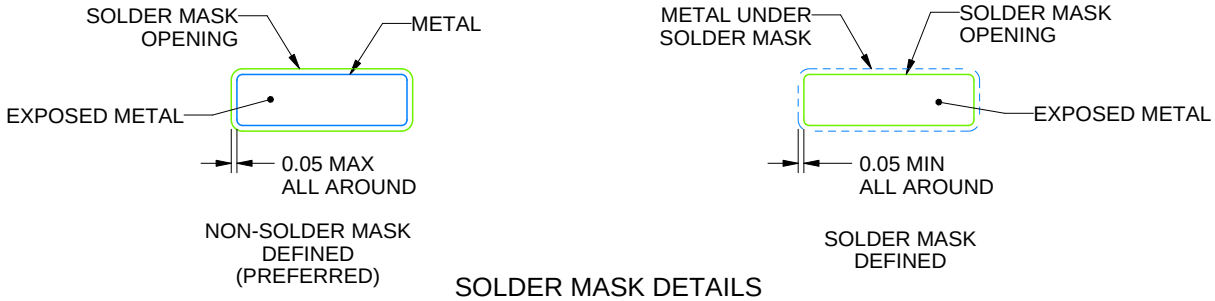


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

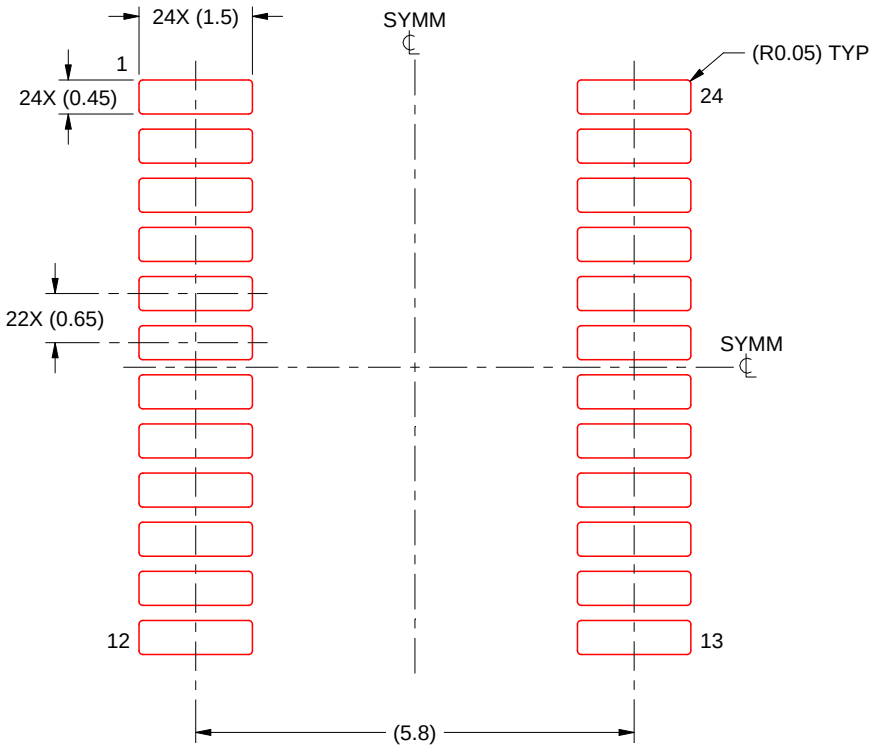


SOLDER MASK DETAILS

4220208/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220208/A 02/2017

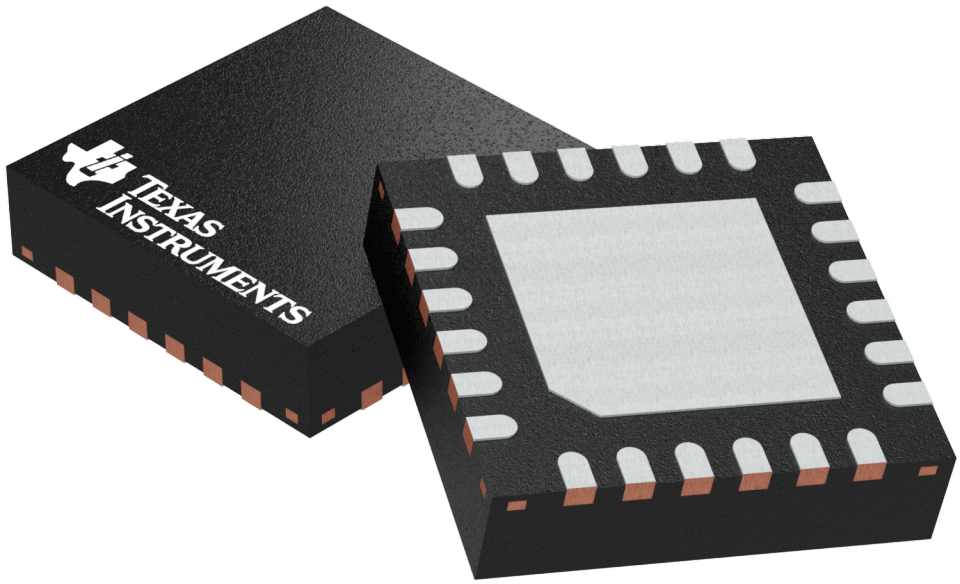
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

RGE 24 VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

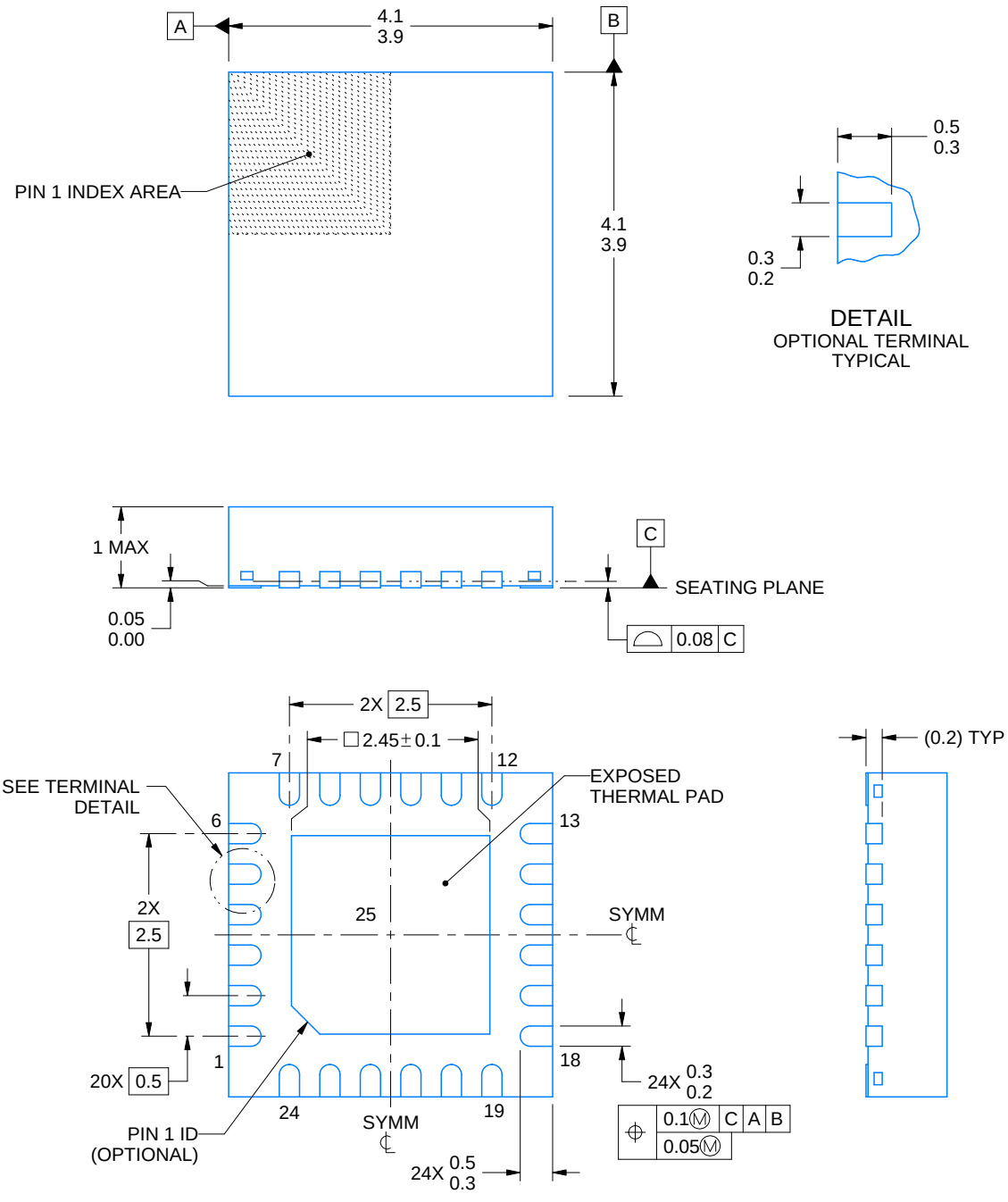
4204104/H

PACKAGE OUTLINE

RGE0024B

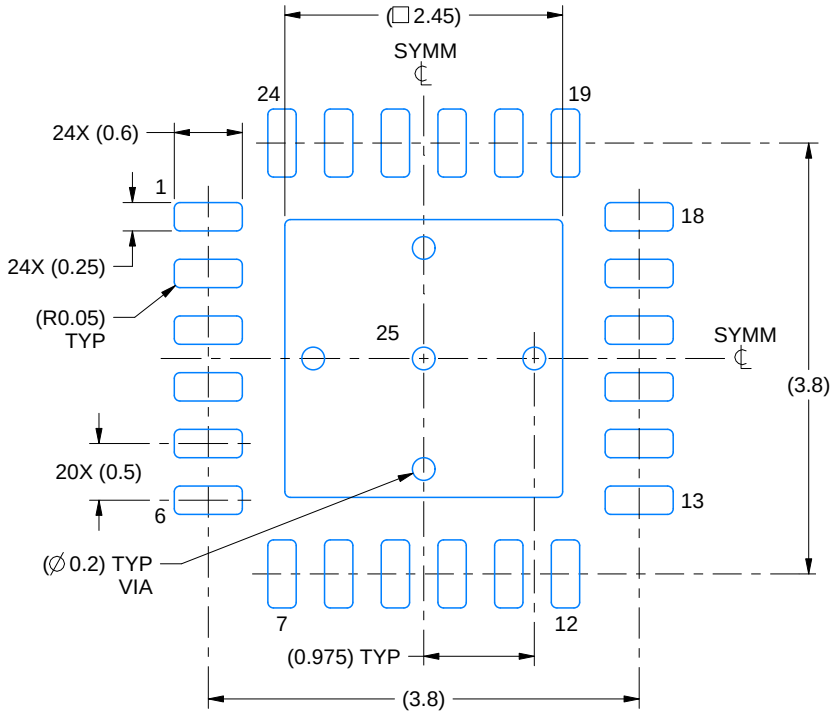
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

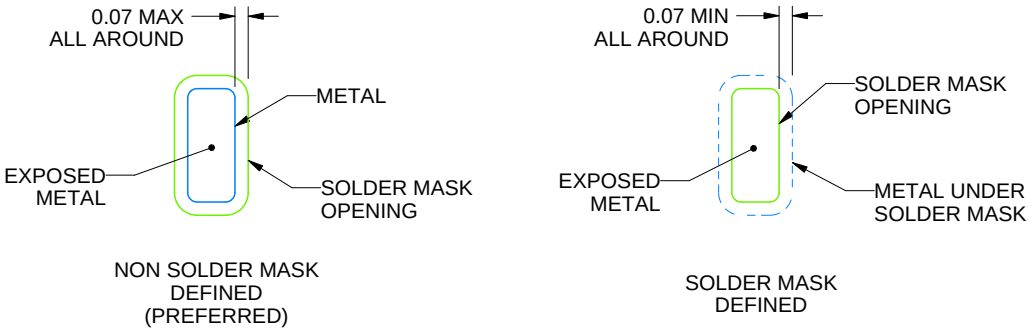


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

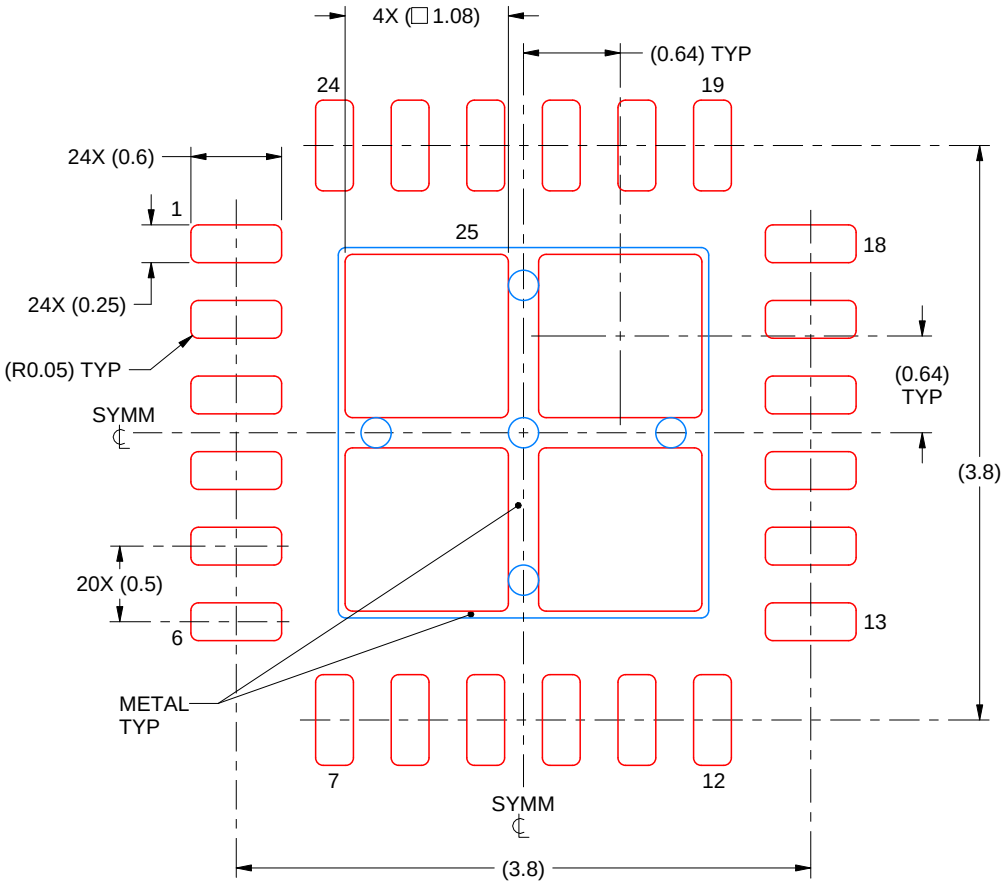


SOLDER MASK DETAILS

4219013/A 05/2017

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 25
78% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:20X

4219013/A 05/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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